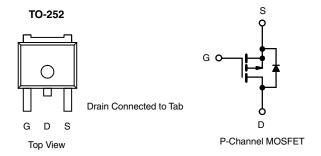


Automotive P-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	- 100			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.040			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.048			
I _D (A)	- 38			
Configuration	Single			



FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- AEC-Q101 Qualifiedd
- 100 % Rq and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



ORDERING INFORMATION				
Package	TO-252			
Lead (Pb)-free and Halogen-free	SQD40P10-40L-GE3			

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V_{DS}	- 100	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C	1	- 38		
	T _C = 125 °C	- I _D	- 22		
Continuous Source Current (Diode Conduction) ^a		I _S	- 50	Α	
Pulsed Drain Current ^b		I _{DM}	- 150		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	- 44		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	96	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	- P _D	136	W	
	T _C = 125 °C		45	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	50	°C/W	
Junction-to-Case (Drain)		R _{thJC}	1.1	- C/VV	

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.



Automotive P-Channel 100 V (D-S) 175 °C MOSFET

SPECIFICATIONS ($T_C = 25 ^{\circ}C$,		1		MIN.	1		
PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		- 100	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V_{GS} , $I_{D} = -250 \mu A$	- 1.0	- 2.0	- 2.5	V
Gate-Source Leakage	I _{GSS}	$V_{DS} =$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = - 100 V	-	-	- 1	μΑ
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -100 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	- 50	
		$V_{GS} = 0 V$	$V_{DS} = -100 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	-	- 250	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = - 10 V	$V_{DS} \le -5 \text{ V}$	- 30	-	-	Α
		V _{GS} = - 10 V	I _D = - 9.2 A	-	0.033	0.040	
Drain Course On Ctate Desistance	B	$V_{GS} = -10 \text{ V}$	I _D = - 9.2 A, T _J = 125 °C	-	-	0.074	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V	I _D = - 9.2 A, T _J = 175 °C	-	-	0.093	. 12
		$V_{GS} = -4.5 \text{ V}$	I _D = - 7.7 A	-	0.037	0.048	
Forward Transconductance ^b	9 _{fs}	V _{DS} =	- 15 V, I _D = - 9.2 A	-	35	-	S
Dynamic ^b	_						
Input Capacitance	C _{iss}			-	4433	5545	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = -25 \text{ V, f} = 1 \text{ MHz}$	-	301	380	pF
Reverse Transfer Capacitance	C _{rss}]		-	208	260	
Total Gate Charge ^c	Qg			-	96	144	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = - 10 V	$V_{DS} = -50V$, $I_{D} = -9.2$ A	-	8.4	-	nC
Gate-Drain Charge ^c	Q _{gd}]		-	23.5	-	
Gate Resistance	R _g		f = 1 MHz		3.13	4.7	Ω
Turn-On Delay Time ^c	t _{d(on)}		V _{DD} = - 50 V, R _I = 6.49 Ω		11	17	
Rise Time ^c	t _r	V _{DD} =			11	17	ns
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong -7.7 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1.0 \Omega$		-	78	117	
Fall Time ^c	t _f			-	15	23	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed Current ^a	I _{SM}			-	_	- 150	Α
Forward Voltage	V_{SD}	I _F = - 7.7 A, V _{GS} = 0 V		-	- 0.8	- 1.5	V

Notes

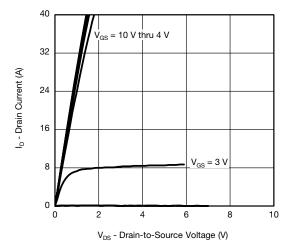
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

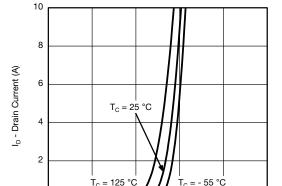


Automotive P-Channel 100 V (D-S) 175 °C MOSFET

TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

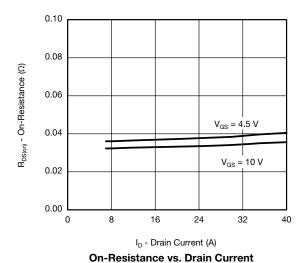


Output Characteristics



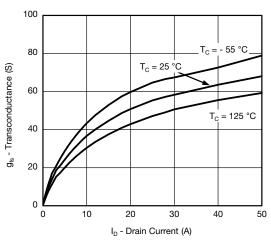
V_{GS} - Gate-to-Source Voltage (V) **Transfer Characteristics**

0

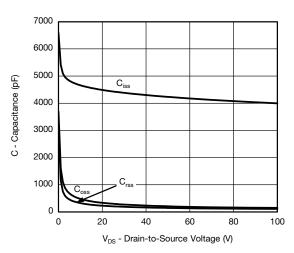


 $T_{\rm C} = 25\,^{\circ}{\rm C}$ $T_{\rm C} = -55\,^{\circ}{\rm C}$

Transfer Characteristics



Transconductance

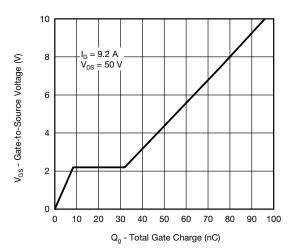


Capacitance

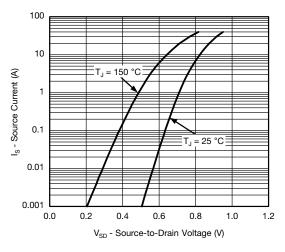


Automotive P-Channel 100 V (D-S) 175 °C MOSFET

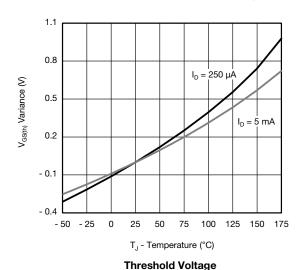
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

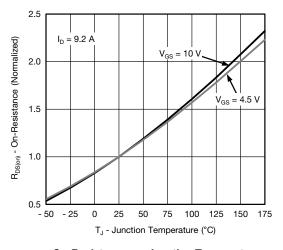


Gate Charge

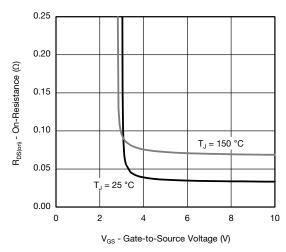


Source Drain Diode Forward Voltage

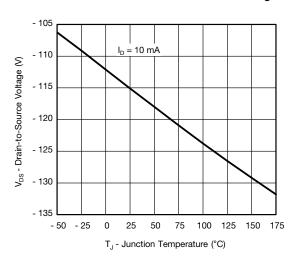




On-Resistance vs. Junction Temperature



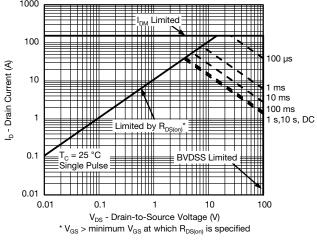
On-Resistance vs. Gate-to-Source Voltage



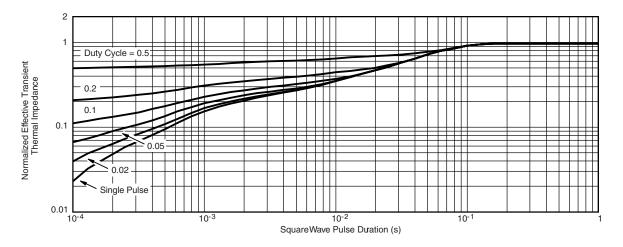
Drain Source Breakdown vs. Junction Temperature

Automotive P-Channel 100 V (D-S) 175 °C MOSFET

THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



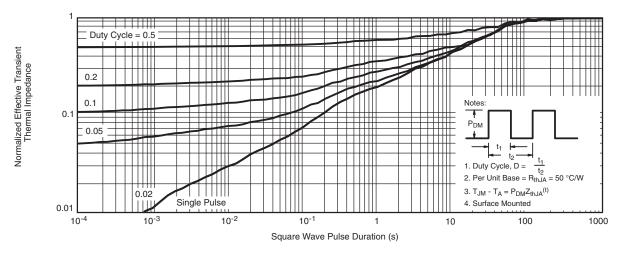
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case

Automotive P-Channel 100 V (D-S) 175 °C MOSFET

THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



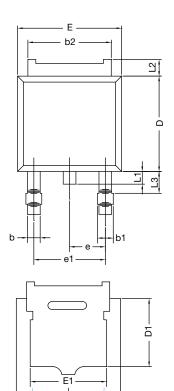
Normalized Thermal Transient Impedance, Junction-to-Ambient

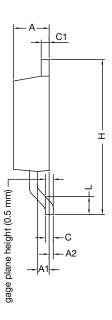
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Automotive P-Channel 100 V (D-S) 175 °C MOSFET

TO-252AA CASE OUTLINE





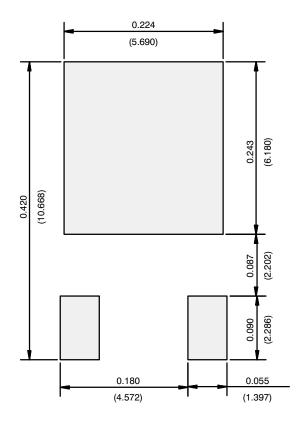
	MILLIMETERS		INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	2.21	2.38	0.087	0.094	
A1	0.89	1.14	0.035	0.045	
A2	0.030	0.127	0.001	0.005	
b	0.71	0.88	0.028	0.035	
b1	0.76	1.14	0.030	0.045	
b2	5.23	5.44	0.206	0.214	
С	0.46	0.58	0.018	0.023	
C1	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.245	
D1	4.10	4.45	0.161	0.175	
Е	6.48	6.73	0.255	0.265	
E1	4.49	5.50	0.177	0.217	
е	2.28 BSC		0.090 BSC		
e1	4.57 BSC		0.180 BSC		
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
L1	0.64	1.02	0.025	0.040	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	
ECN: T11-0110-Rev. L, 18-Apr-11 DWG: 5347					

Note

• Dimension L3 is for reference only.

Automotive P-Channel 100 V (D-S) 175 °C MOSFET

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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Automotive P-Channel 100 V (D-S) 175 °C MOSFET

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